

### Low voltage high performance PNP power transistor

Datasheet — production data

#### **Features**

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Small, thin, leadless SMD plastic package with excellent thermal behavior

#### **Applications**

- Power management
- DC-DC converters

#### **Description**

This device is an PNP transistor manufactured using new low voltage planar technology with double metal process. The result is a transistor which boasts exceptionally high gain performance coupled with very low saturation voltage.

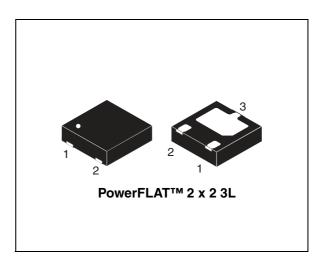


Figure 1. Internal schematic diagram

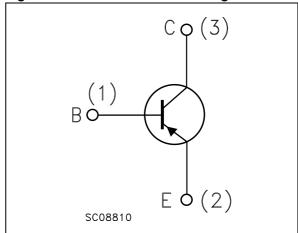


Table 1. Device summary

Order code	Marking	Package	Packaging
3STL2540	L2540	PowerFLAT™ 2 x 2	Tape and reel

### 1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> = 0)	-40	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	-40	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	-6	V
Ic	Collector current	-5	Α
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms)	-10	Α
I <sub>B</sub>	Base current	-0.5	Α
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 5 ms)	-1	Α
P <sub>TOT</sub> <sup>(1)</sup>	Total dissipation at T <sub>A</sub> = 25 °C	1.2	W
T <sub>STG</sub>	Storage temperature	-65 to 150	°C
T <sub>J</sub>	Max. operating junction temperature	150	°C

<sup>1.</sup> Device mounted on a PCB area of 1 cm<sup>2</sup>

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJA</sub> <sup>(1)</sup>	Thermal resistance junction-ambient max	104	°C/W
R <sub>thJA</sub> <sup>(2)</sup>	Thermal resistance junction-ambient max	75	°C/W
R <sub>thJC</sub>	Thermal resistance junction-case max	45	°C/W

<sup>1.</sup> Device mounted on a PCB area of 1 cm<sup>2</sup>

<sup>2.</sup> Device mounted on a PCB area of 6 cm<sup>2</sup>

### 2 Electrical characteristics

 $T_J$  = 25  $^{\circ}\text{C};$  unless otherwise specified.

Table 4. Electrical characteristics

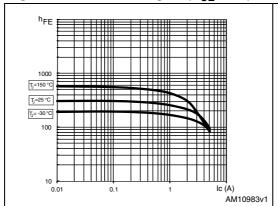
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = - 40 V			-100	nA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = - 6 V			-100	nA
V <sub>BE(on)</sub>	Base-emitter on voltage	$V_{CE} = -2 V$ $I_{C} = -100 \text{ mA}$		-670		mV
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage			-150 -300	-200	mV
V <sub>BE(sat)</sub>	Base-emitter saturation voltage	I <sub>C</sub> = - 1 A		800		mV
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	V <sub>CE</sub> = -2 V I <sub>C</sub> = -0.5 A V <sub>CE</sub> = -2 V I <sub>C</sub> = -2 A V <sub>CE</sub> = -2 V I <sub>C</sub> = -5 A		280 210 100		
		$V_{CE} = -0.2 \div - 2 \text{ V } I_{C} = -1 \text{ A}$ $T_{j} = -30 \text{ °C} \div 150 \text{ °C}$	100		900	
t <sub>d</sub> t <sub>r</sub> t <sub>s</sub>	Resistive load Delay time Rise time Storage time Fall time	$I_{C} = -2 A$ $V_{CC} = -10 V$ $V_{BE(off)} = 5 V$ , $-I_{B(on)} = I_{B(off)} = 200 \text{ mA}$		25 140 290 60		ns ns ns
f <sub>T</sub>	Transition frequency	I <sub>C</sub> = - 0.1 A V <sub>CE</sub> = - 10 V		130		MHz

<sup>1.</sup> Pulse test: pulse duration ≤300 µs, duty cycle ≤2 %.

Electrical characteristics 3STL2540

### 2.1 Electrical characteristics (curves)

Figure 2. DC current gain (V<sub>CE</sub>=-2 V) Figure 3. DC current gain (V<sub>CE</sub>=-5 V)



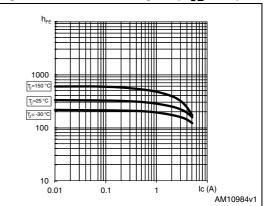
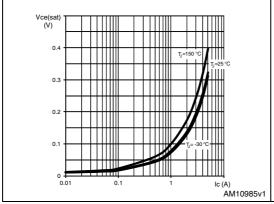


Figure 4. Collector-emitter saturation voltage (V<sub>CEsat</sub> @ h<sub>FE</sub>=20)

Figure 5. Collector-emitter saturation voltage (V<sub>CEsat</sub> @ h<sub>FE</sub>=100)



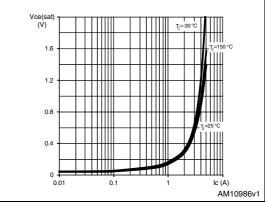
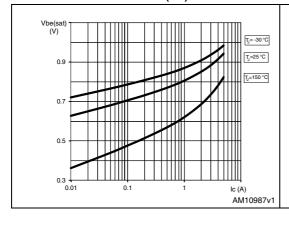


Figure 6. Base-emitter saturation voltage ( $V_{be(sat)}$  @  $h_{FE}$ =20)

Figure 7. Base-emitter saturation voltage ( $V_{be(sat)}$  @  $h_{FE}$ =100)



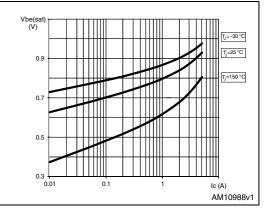
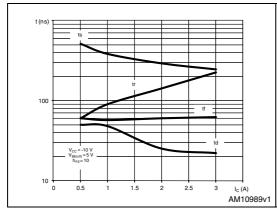
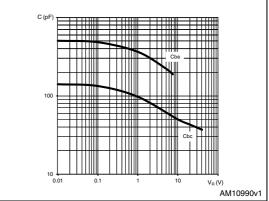


Figure 8. Resistive load switching times

Figure 9. Capacitance curves (f=1 MHz)





# 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 5. PowerFLAT™ 2 x 2 3L mechanical data

Dim.	mm.			
	Min.	Тур.	Max.	
А	0.55	0.60	0.65	
A1	0.00	0.02	0.05	
А3		0.10		
b	0.25	0.30	0.35	
D	1.90	2.00	2.10	
E	1.90	2.00	2.10	
е	1.20	1.30	1.40	
D2	0.95	1.05	1.15	
E2	1.40	1.50	1.60	
Н	0.20	0.25	0.30	
K	0.20	0.30	0.40	
L	0.35	0.40	0.45	
R	0.15			

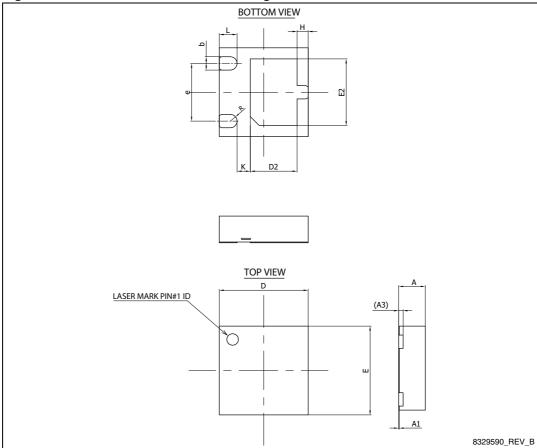


Figure 10. PowerFLAT™ 2 x 2 3L drawing

# 4 Packaging mechanical data

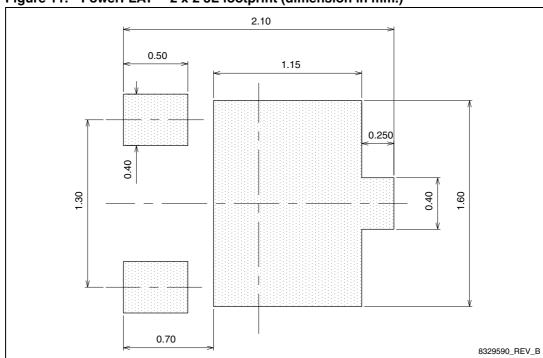


Figure 11. PowerFLAT™ 2 x 2 3L footprint (dimension in mm.)

Revision history 3STL2540

# 5 Revision history

Table 6. Document revision history

Date	Revision	Changes
07-Dec-2011	1	Initial release
22-May-2012	2	Document status promoted from preliminary data to production data

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